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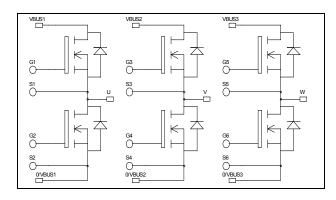








# Triple phase leg MOSFET Power Module



$$\begin{split} V_{DSS} &= 100V \\ R_{DSon} &= 19 m\Omega \text{ typ @ Tj} = 25^{\circ}C \\ I_D &= 70 \text{A @ Tc} = 25^{\circ}C \end{split}$$

#### Application

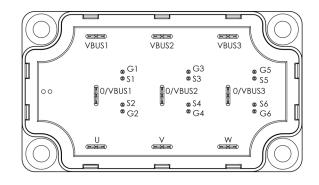
- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

#### **Features**

- Power MOS V® FREDFETs
  - Low R<sub>DSon</sub>
  - Low input and Miller capacitance
  - Low gate charge
  - Fast intrinsic diode
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - Lead frames for power connections
- High level of integration

#### **Benefits**

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Very low (12mm) profile
- Each leg can be easily paralleled to achieve a phase leg of three times the current capability
- Module can be configured as a three phase bridge
- Module can be configured as a boost followed by a full bridge
- RoHS Compliant



#### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		100	V
т	Continuous Drain Current	$T_c = 25$ °C	70	
$I_D$	Continuous Drain Current	$T_c = 80$ °C	50	Α
$I_{DM}$	Pulsed Drain current		300	
$V_{GS}$	Gate - Source Voltage		±30	V
R <sub>DSon</sub>	Drain - Source ON Resistance		21	mΩ
$P_{D}$	Maximum Power Dissipation $T_c = 25^{\circ}C$		208	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)		75	A
E <sub>AR</sub>	Repetitive Avalanche Energy		30	ma I
$E_{AS}$	Single Pulse Avalanche Energy		1500	mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

www.microsemi.com



### All ratings @ $T_j = 25$ °C unless otherwise specified

#### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$ $T_j = 25^{\circ}C$			250	μА
		$V_{GS} = 0V, V_{DS} = 80V$ $T_j = 125^{\circ}C$			1000	
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 35A$		19	21	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 1 \text{mA}$	2		4	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			±100	nA

**Dynamic Characteristics** 

•	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		5100		
$C_{oss}$	Output Capacitance	$V_{DS} = 25V$		1900		pF
$C_{rss}$	Reverse Transfer Capacitance	f = 1MHz		800		
$Q_{g}$	Total gate Charge	$V_{GS} = 10V$		200		
$Q_{gs}$	Gate – Source Charge	$V_{Bus} = 100V$		40		nC
$Q_{\text{gd}}$	Gate – Drain Charge	$I_D = 70A$		92		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		35		
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$		70		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 66V$ $I_{\text{D}} = 70A$		95		ns
$T_{\mathrm{f}}$	Fall Time	$R_G = 5\Omega$		125		
$E_{on}$	Turn-on Switching Energy	Inductive switching @ 25°C		276		
$E_{\text{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 70A, R_G = 5\Omega$		302		μJ
$E_{on}$	Turn-on Switching Energy	Inductive switching @ 125°C		304		T .
E <sub>off</sub>	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 70A, R_G = 5\Omega$		320		μJ

#### Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
$I_S$	Continuous Source current		$Tc = 25^{\circ}C$			70	Α	
ıs	(Body diode)		$Tc = 80^{\circ}C$			50	Λ	
$V_{\mathrm{SD}}$	Diode Forward Voltage	$V_{GS} = 0V, I_S = -70A$				1.3	V	
dv/dt	Peak Diode Recovery •					5	V/ns	
t	Reverse Recovery Time		$T_j = 25^{\circ}C$			200	ns	
$t_{rr}$	Reverse Recovery Time	$I_{S} = -70A$ $V_{Bus} = 66V$	$T_j = 125$ °C			350	115	
Q <sub>rr</sub>	Reverse Recovery Charge	$di_{S}/dt = 100A/\mu s$	$T_j = 25^{\circ}C$	= 25°C 0.:	5°C 0.5		μС	
	Reverse Recovery Charge		$T_j = 125$ °C		1		μ	

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

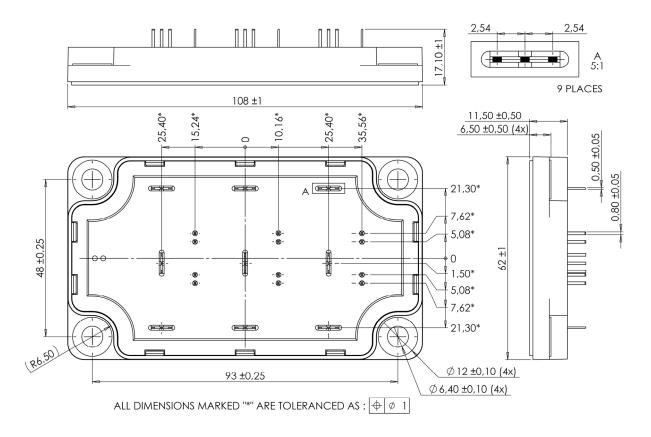
 $I_S \leq \text{- }70A \qquad di/dt \leq 700A/\mu s \qquad V_R \leq V_{DSS} \qquad T_j \leq 150^{\circ}C$ 



#### Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
$R_{thJC}$	Junction to Case Thermal Resistance					0.6	°C/W
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range		-40		150		
T <sub>STG</sub>	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
Wt	Package Weight					250	g

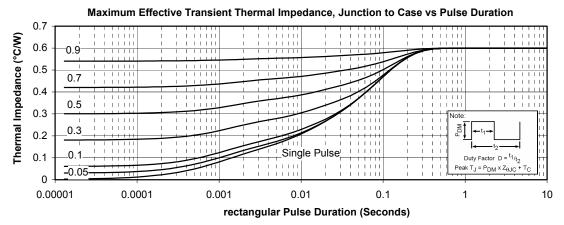
### SP6-P Package outline (dimensions in mm)

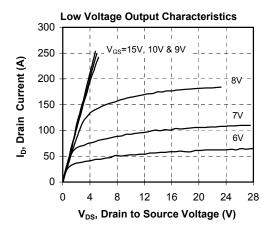


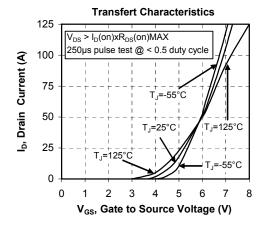
See application note 1902 - Mounting Instructions for SP6-P (12mm) Power Modules on www.microsemi.com

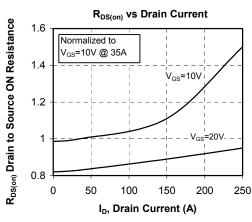


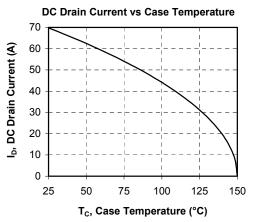
### **Typical Performance Curve**



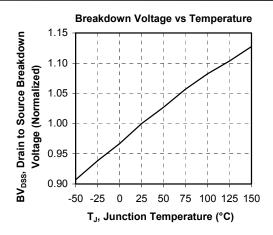


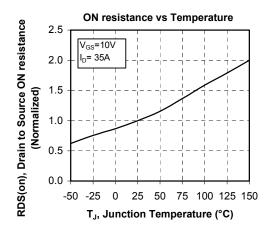


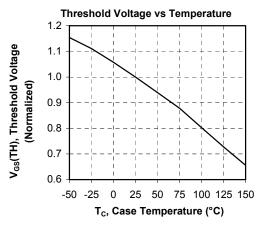


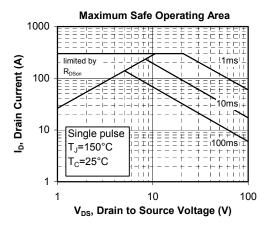


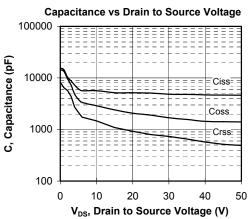


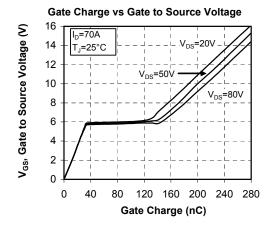




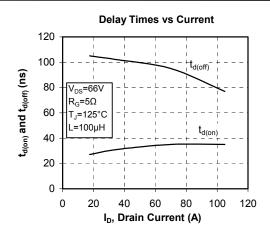


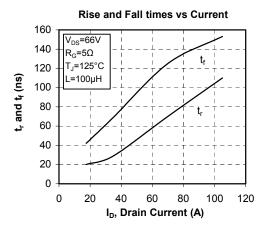


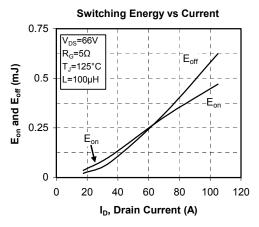


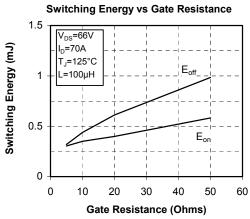


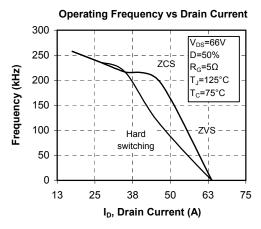


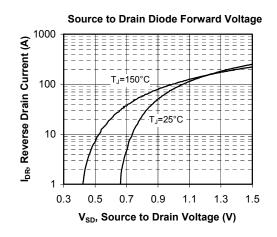












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